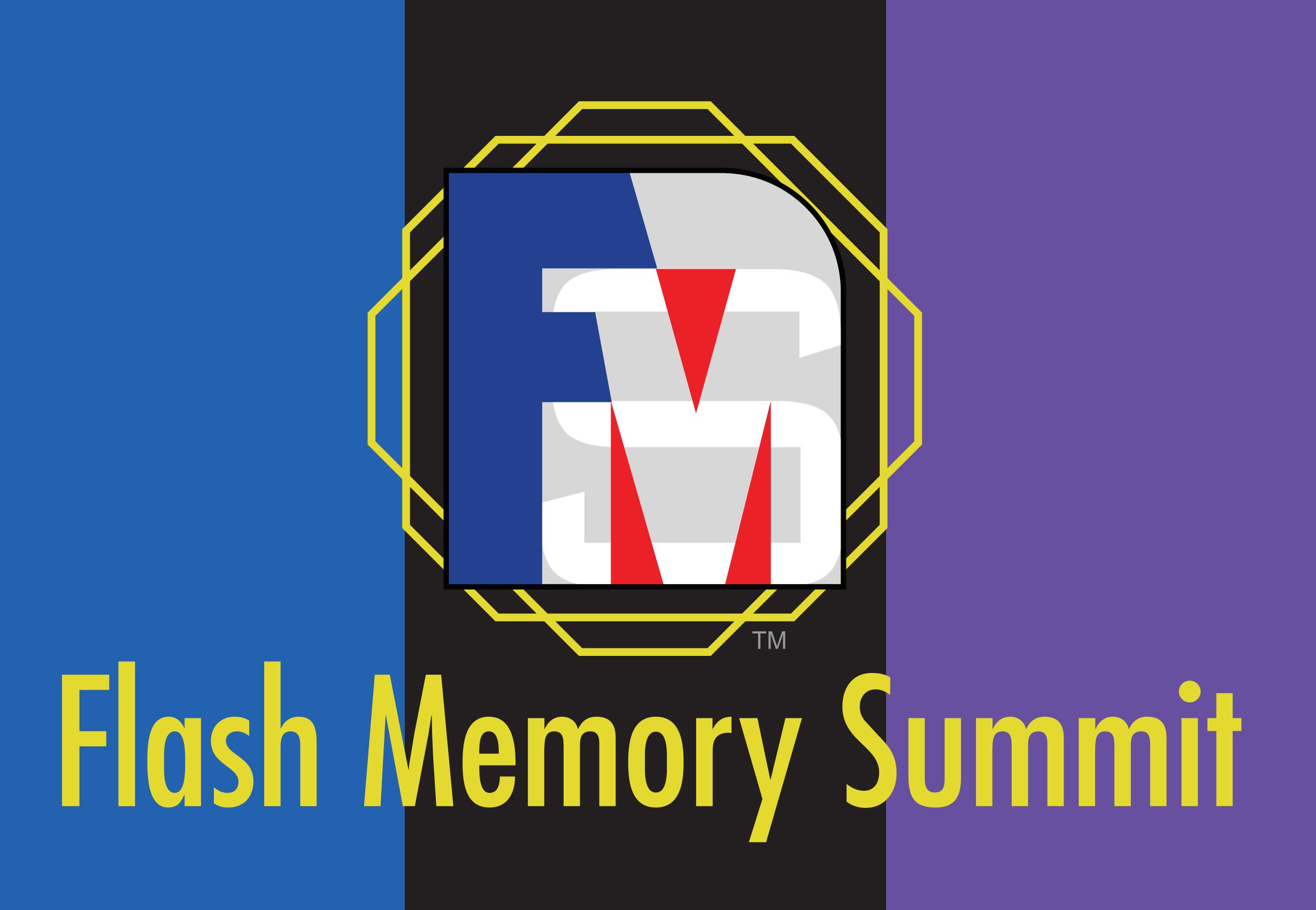
# 1955 1955 1961

MIT's Dudley
Buck creates first
semiconductor NVM
from ferroelectric
crystals.

Bell Labs' Merz and Anderson create monolithic 256-bit FRAM ferroelectric NVM, the first monolithic memory chip. C.T. "Tom" Sah of Fairchild envisions floating gate NVM using charge storage on the gate electrode of a MOS tetrode transistor.







Dov Frohman-Bentchkowsky writes
Berkeley PhD thesis
"Charge Transport and Trapping in MNOS
Structures and its
Memory Applications" and builds a 9-bit prototype.

Edgar A. Sack, Ting
L. Chu and others
of Westinghouse
use a Metal-NitrideOxide-Silicon (MNOS)
structure as a chargetrapping element.

Dawon Kahng and Simon Sze (2014 FMS Lifetime Achievement Awardee) invent the Non-Volatile Memory Floating Gate at Bell Labs; this is published as "A Floating Gate and Its Application to Memory Devices" (Bell System Technical Journal).

John R. Szedon (2020 FMS Lifetime Achievement Awardee) and Ting L. Chu of Westinghouse propose using a charge trap as a nonvolatile memory bit at the IEEE Solid State Device Research Conference. Stanford R. Ovshinsky announces the Ovonic Memory Switch, the basis for 3D XPoint memory as announced by Intel and Micron in 2015, and as later productized by Intel as Optane.



Dov Frohman-Bentchkowsky invents the Erasable Programmable Read-Only Memory (EPROM) at Intel; this is presented at the 1971 IEEE International Solid-State Circuits Conference (ISSCC), and is published as "Memory Behavior in a Floating-Gate Avalanche-Injection MOS (FAMOS) Structure" in April 1971 (Applied Physics Letters), which cited the 1967 Kahng/ Sze Bell Labs Floating Gate publication.

After work with
Stanford R. Ovshinsky,
Intel's Gordon Moore
co-authors article for
Electronics Magazine on
the first demonstration
of Phase Change
Memory (PCM), the
NVM technique used
by 3D XPoint as
announced by Intel and
Micron in 2015, and as
later productized by
Intel as Optane.

Toshiba's lizuka, Masuoka and others introduce the first double-layered polysilicon memory cell with Floating Gate electrical erase as Stacked-Gate Avalanche-Injection Type MOS (SAMOS) Memory at International Conference on Solid State Devices and Materials. Fujio Masuoka goes on to receive the 2013 FMS Lifetime Achievement Award.

General instrument ships EAROM, the first commercial EEPROM.

Hitachi files for patent on NAND-type MROM.

Portable digital camera invented at Eastman Kodak Company with digital image storage on a cassette tape.



Eli Harari (2012 and 2022 FMS Lifetime Achievement Awardee), then of Hughes Microelectronics, files for patent on first practical floating gate EEPROM using thin SiO2 and Fowler-Nordheim tunneling for program and erase.

Eli Harari (2012 and 2022 FMS Lifetime Achievement Awardee), then of Hughes Microelectronics, publishes "Conduction and Trapping of Electrons in Highly Stressed Thin Films of Thermal SiO<sub>2</sub>" (Applied Physics Letters).

P.C.Y. Chen of Fairchild introduces SONOS charge trap NVM cell in IEEE Transactions on Electron Devices.

Patent granted to Tl's
Gerald Rogers for mask
ROM configured as a
NAND array to reduce
chip area and cost.

Eli Harari (2012 and 2022 FMS Lifetime Achievement Awardee), then of Hughes Microelectronics, publishes "Dielectric Breakdown in Electrically Stressed Thin Films of Thermal SiO<sub>2</sub>" (Journal of Applied Physics).

Hughes
Microelectronics
introduces first CMOS
NOVRAM 256-bit chip
(non-volatile SRAM)
employing Fowler
Nordheim floating gate
EEPROM at IEEE
ISSCC.

George Perlegos
(2017 FMS Lifetime
Achievement Awardee)
designs the Intel 2816,
which was introduced
in 1980 and became
the first commercially
successful EEPROM.

IEEE Solid State Circuits publishes paper titled "An Electrically Alterable Non-Volatile Memory Cell Using Floating Gate Structure" by Guterman, Rinawi, Chieu, Holvorson, and McElroy of Texas Instruments.



Hughes
Microelectronics
introduces the 3108,
first CMOS EEPROM
8Kb chip employing
Fowler Nordheim
tunneling.

Intel introduces
the 2816, a 16Kb
HMOS EEPROM
with a FLOTOX (floating
gate tunnel oxide)
structure employing
Fowler-Nordheim
tunneling, at IEEE
ISSCC.

Fujitsu files for patent on improvements to Hitachi's 1975 MROM.

British scientist and inventor Kane Kramer designs first digital audio player (IXI) based on magnetic bubble memory chips.

SEEQ Technology introduces the 5213, the first EEPROM with an on-chip charge pump for in-system write and erase, an invention used in all flash memory devices.

Ramtron introduces first commercial FRAM NVM.

Intel introduces 2817A 16Kb EEPROM.



### Annual Flash Chip Revenue >

\$1,600,000

First paper describing flash EEPROM presented by Toshiba's Fujio Masuoka (2013 FMS Lifetime Achievement Awardee) at IEEE International Electron Devices Meeting (IEDM) in San Francisco.

Intel begins flash process development.

George Perlegos
(2017 FMS Lifetime
Achievement Awardee)
founds ATMEL
(which stands for
"Advanced Technology
for Memory and Logic").

Exel files for patent on first NOR Flash cell.

NEC's Kitamura files for first MLC (Multi-Level Cell) EPROM patent (in Japan).

Flash card concept introduced with ECC and on-card controller by Intel.

Intel forms unit focusing on solid state drives.

R. Stewart et. al. of RCA publish first paper on a NAND-configured UV-EPROM at IEEE VLSI Symposium.

Toshiba's Fujio
Masuoka (2013 FMS
Lifetime Achievement
Awardee) presents
IEEE IEDM paper on
NAND flash memory;
the 35th anniversary of
his inventive paper was
celebrated at the 2022
FMS.

Intel introduces NOR flash chips.



\$170,000,000

SunDisk founded by Eli Harari (2012 and 2022 FMS Lifetime Achievement Awardee) to develop new "System Flash" architecture combining embedded controller, firmware and flash to emulate disk storage, and

files for first MLC (Multi-

Level Cell) flash patent.

First flash memory sampled by Intel as 1Mb NOR chips. Intel's Design Team of Richard Pashley, Stefan Lai, Bruce McCormick and Niles Kynett go on to receive 2012 FMS Lifetime Achievement Awards.

Intel and Psion design flash-based mobile PC.

First flash-based digital camera, Fuji DS-1P, demonstrated.

150mm wafers used.

SunDisk files for patent on "System Flash" which describes on-chip cell management.

M-Systems founded and introduces Flash Disk concept (precursor to flash SSDs); M-Systems co-founders Dov Moran and Aryeh Mergi went on to receive 2018 FMS Lifetime Achievement Awards.

Intel ships 512Kb and 1Mb NOR flash.

Psion flash-based PC introduced.

Microsoft introduces
Flash File System in joint effort with Intel.

DigiPro introduces
8MB NOR Flashdisk at
Comdex.

Western Digital and SunDisk pioneer NOR-based SSD fully emulating ATA HDD.

Personal Computer
Memory Card
International
Association (PCMCIA)
founded.

Silicon Storage
Technology (SST)
founded to produce
NOR SuperFlash,
compatible with a
CMOS logic process.

Sony introduces
EReader using flash
memory.

Kodak flash-based camera prototypes shown.

PCMCIA sets
standard on ATA PC
Card form factor
and pinout, using
SunDisk "System Flash"
specification for full
HDD compatibility.

Intel 1MB and 4MB linear flash PCMCIA cards introduced.

Intel introduces 2Mb NOR chip.

SunDisk introduces first NOR flash SSD: 20MB 2.5", fully compatible with Conner peripherals 2.5" ATA HDD.

Toshiba verifies NAND flash chip operation, and begins 4Mb and 16Mb NAND flash chip development.

Kodak ships DCS-100, its first DCS at \$13,000.

Zenith, Poqet and HP palm-sized notebook computers using flash memory cards shown at Spring Comdex.



\$295,000,000

Toshiba ships 16Mb

\$505,000,000

\$864,805,000

\$1,860,089,000

Toshiba ships first mass-produced NAND flash chips (4Mb).

Information Storage Devices introduces flash-based voice recorder chip.

AMD introduces its first NOR product.

Fujitsu introduces its first NOR product.

M-Systems introduces TrueFSS, the first flash memory card FTL; this was later adopted by the PCMCIA as its FTL.

Intel launches secondgeneration FFS2.

Intel introduces 8Mb NOR flash chips and 4MB-20MB linear flash memory cards.

Intel introduces 1Mb "boot block" NOR flash with sectors for BIOS applications—first use of internal write state machine to manage flash write algorithm.

SunDisk introduces first serial 9Mb NOR Flash chip for SSD applications.

PCs begin using flash for BIOS storage.

The Joint Photographic Experts Group published the JPEG standard, enabling digital cameras to store compressed photos using media such as flash memory.

NAND flash chips, which enable portable storage with the first PCMCIA cards.

Datalight introduces "Card Trick" flash management software.

Apple introduces NOR flash-based Newton PDA.

Intel introduces 16Mb and 32Mb NOR flash.

Intel and Conner Peripherals introduce jointly-developed 5MB/10MB ATA flash disk drive.

AMD introduces 5-volt-only NOR using negative gate erase.

SunDisk introduces CompactFlash card.

Norris Communications introduces Flashback, the first portable digital voice recorder with flash memory.

0.5 micron process announced.

SunDisk introduces 18Mb Serial NOR flash chip for SSD applications.

M-Systems introduces NOR-based DiskOnChip.

Flash (NOR and NAND) revenues exceed \$1B.

Casio introduces the QV-11 digital camera with flash rather than film or floppy.

Mitsubishi introduces DINOR.

SunDisk changes name to SanDisk.

CompactFlash Association (CFA) founded.



\$2,610,603,000

\$2,701,678,000

NIOD rovonuos ovecod

\$2,492,552,000

\$4,560,493,000

\$2.6B in flash memory revenues, 163,063% growth in 10 years.

Toshiba introduces
SmartMedia Memory
Card (also called Solid
State Floppy Disk Card).

Samsung starts shipping NAND flash.

Kodak DC-25 is
first DSC with
CompactFlash card.

Datalight introduces
"FlashFX" flash
management software
supporting NOR and
NAND in a single driver.

SanDisk introduces world's first MLC (2 bits/cell) flash chip (80 Mb) in a CompactFlash (CF) card.

Palm introduces flash memory-based PDA.

0.35 micron process announced.

Lexar Media spins off from Cirrus Logic.

USB Association (USBA) founded.

500 million flash chips ship.

SaeHan Information
Systems introduces
flash-based MPMan
MP3 player.

SanDisk and
Siemens introduce
MultiMedia Card (MMC and MMCplus).

Sony introduces the Memory Stick.

First cell phones ship with flash memory.

M-Systems introduces NAND-based DiskOnChip.

200mm wafers begin production.

SanDisk begins using 256 Mb MLC flash chips in its CompactFlash (CF) cards.

Intel introduces
2-bit/cell 64Mb MLC
StrataFlash chip.

MultiMediaCard (MMC) unveiled by SanDisk and Siemens.

SanDisk begins transition from NOR to NAND flash.

NOR revenues exceed \$2B.

250nm process announced.

SaeHan Information Systems and licensee Eiger ship first massproduced MP3 player (MPMan) with 32MB.

Diamond Rio introduces PMP300 MP3 player.

MultiMediaCard
Association (MMCA)
founded by 14
companies.

Apple iMac introduced without floppy but with USB, encouraging USB-based external storage.

USB Implementers
Forum first publishes
USB Mass Storage Class
spec (finalized in 1999)
to standardize USBbased storage.

NOR revenues exceed \$4B.

Over one billion flash chips ship.

Toshiba and SanDisk create flash memory manufacturing joint venture.

Micron announces NOR products.

Hagiwara Sys-Com begins shipping FlashGate, a USB SmartMedia flash memory card drive.

Dov Moran (2018 FMS Lifetime Achievement Co-Awardee) is co-inventor on M-Systems patent filing for USB flash drive.

Lexar Media introduces
CompactFlash-to-USB
JumpSHOT.

Panasonic (Matsushita), SanDisk and Toshiba introduce SD memory card.

## \$10,637,231,000 \$7,594,502,000 \$11,739,282,000 \$7,766,797,000

Olympus and FujiFilm

Flash (NOR and NAND) revenues exceed \$10B.

M-Systems (working with IBM) and Trek Technology introduce USB flash drives.

Intel ships its onebillionth flash unit.

160nm process announced.

Panasonic (Matsushita), SanDisk and Toshiba establish SD Association to standardize and promote the Secure Digital memory card.

SLC NAND-based SD cards introduced in 8MB to 64MB capacities.

NAND revenues exceed \$1B.

Toshiba and SanDisk announce 1Gb MLC NAND.

SanDisk introduces first NAND "System Flash" product.

Hitachi introduces AG-AND.

Samsung begins mass production of 512Mb flash memory device.

Saifun develops NROM with charge trap flash structure, the basis for Spansion's MirrorBit.

introduce xD-Picture Card.

MMCmoblie card introduced by MMCA (MultiMediaCard Association).

Sony and SanDisk jointly introduce the Memory Stick PRO and half-size Memory Stick PRO Duo cards.

M-Systems introduces Mobile DiskOnChip, the first SSD in a chip; this was used in handsets by Nokia, Motorola and Ericsson.

AMD introduces MirrorBit using hot electron injectionbased charge trap flash.

Cypress introduces Programmable System on Chip (PSoC) with first embedded SONOS using quantum mechanical tunnelingbased charge trap flash.

130nm process announced.

NAND revenues exceed \$5B.

SanDisk introduces miniSD card.

Sony and SanDisk jointly introduce Memory Stick PRO Micro.

Spansion spins out of AMD and Fujitsu.

Samsung introduces TaNOS structure at IEEE IEDM, a technology later used in 3D NAND.

Email suggested additions and changes to timeline@FlashMemorySummit.com

Flash Memory Summit is not responsible for any inaccuracies in this Timeline.

\$15,610,575,000 \$18,568,940,000 \$20,076,313,000 \$22,182,405,000

NAND prices drop below DRAM prices.

U3 software system for USB flash drives introduced by SanDisk and M-Systems.

SanDisk and
Motorola introduce
TransFlash card, now
the microSD card.

Datalight introduces multi-threaded "FlashFX Pro." management software to support multimedia NAND devices.

Spansion announces
MirrorBit Quad 4-bit
NOR.

90nm process announced.

Hynix and ST Micro form flash joint venture.

Hynix NAND product introduced.

Infineon NAND product introduced based on Saifun Charge Trap Flash.

Panasonic and Sanyo introduce first flash-based camcorders.

SanDisk introduces
Flash Sansa MP3
players.

Freescale (later Everspin) ships first commercial MRAM NVM.

Pankaj Mehra and Sam Fineberg of Hewlett-Packard present Persistent Memory paper at IEEE Computer Society's 18th IPDPS. NAND revenues exceed \$10B.

Over three billion flash chips ship.

NAND GB shipments overtake those of DRAM.

Apple introduces first two flash-based iPods: iPod shuffle and iPod nano.

Microsoft introduces
Hybrid Hard Disk Drive
concept.

MMCmicro card introduced by MMCA.

70nm process announced.

Micron introduces
NAND product.

Flash revenues exceed \$20B.

First Flash Memory
Summit held in
San Jose.

Intel introduces Robson
Cache Memory (now
called Turbo Memory).

Microsoft introduces ReadyBoost.

SanDisk announces
3-bit MLC (aka TLC)
NAND technology.

M-Systems announces
4-bit MLC technology.

SanDisk announces microSDHC card.

SanDisk acquires Matrix Semiconductor.

SanDisk acquires M-Systems.

Samsung and Seagate demonstrate first Hybrid Hard Disk Drives.

IMFT formed by Intel and Micron to manufacture NAND flash.

STEC acquires Gnutech.

Spansion introduces ORNAND flash.

56nm process announced.

300mm wafers begin production.

Micron acquires Lexar Media.

Open NAND Flash
Interface (ONFi) V1.0
spec published.

Numonyx and Samsung introduce phase change NVM.

Flash revenues exceed \$22B, almost 9 times 1997 revenues.

NAND revenues exceed \$14.5B.

Non-Volatile Memory
Host Controller
Interface (NVMHCI)
Working Group formed,
with Intel's Amber
Huffman as Chair.

Toshiba introduces eMMC NAND.

IMFT begins shipping 50nm NAND flash.

Toshiba introduces
first SATA-based MLC
SSD.

Apple introduces the iPhone.

Fusion-io announces 640GB ioDrive MLC NAND-based PCIe X4 board.

BiTMICRO launches 3.5" SSD with capacity of 1.6TB (for military applications).

Spansion acquires Saifun.

Several laptop MLC SSDs introduced with up to 128GB storage.

Dell introduces SSD option for laptop models.

Sub-\$200 netbook computers introduced with flash memory storage.

Microsoft introduces flash-based Zune Player.

Seagate announces
Hybrid Storage Alliance.

Seagate introduces first hybrid HHD, the Momentus PSD.

MMCA/JEDEC e.MMC spec published.

Toshiba presents 3D flash BiCS memory at IEEE VLSI Symposium.



\$18,435,970,000 \$19,302,693,000 \$26,734,247,000 \$28,123,615,000

NVMHCI 1.0 Spec released by Intel.

SanDisk introduces ABL to enable high speed MLC, TLC and X4 NAND.

34nm process announced by Intel and Micron.

Toshiba introduces first 512GB MLC SATA-based SSD.

Intel and STMicro spin off Numonyx.

IBM demos first "Million IOPS" array.

EMC announces use of flash-based SSDs for enterprise SAN applications.

Apple introduces SSD-based MacBook Air with no HDD option.

Micron, Samsung and Sun Microsystems announce highendurance flash memory.

Violin Memory introduces first fully flash-based storage appliance.

Samsung announces 150GB 2.5" MLC SSD with SATA II Interface.

Several companies announce MLC flash SSDs with up to 256GB for notebook apps.

Micron introduces first serial NAND flash.

Apple sells one million flash-based iPhones in 3 days.

MMCA merges into JEDEC.

SNIA Solid State Storage Initiative (SSSI) formed.

HGST releases first SSD with a SAS interface.

Intel and Micron introduce 34nm TLC NAND.

Samsung introduces first full HD camcorder with 64GB SSD.

Seagate enters SSD market.

SandForce
introduces first
compression-based
SSD controller.

Virident and Schooner introduce first flash-based application appliances for the data center.

Pillar Data converts
Axiom SANs to SSD.

SanDisk and Toshiba present 4-bit/cell flash at IEEE ISSCC.

WD acquires
SiliconSystems and gets
into SSD business.

NVELO introduces
first PC flash caching
software "Dataplex."

SanDisk introduces
100-year flash storage
vault.

AgigA ships NAND-backed DIMM.

Toshiba introduces
128GB SD card based
on 16-chip stack.

Intel, Micron introduce 25nm TLC and MLC NAND.

Numonyx acquired by Micron.

Microchip acquires SST.

Samsung Electronics begins producing 64Gb 3-bit NAND.

Samsung Electronics introduces high-speed 512GB SSD utilizing toggle-mode DDR NAND memory.

Seagate announces first self-managed hybrid HDD, Momentus XT, with 4GB NAND flash and 500GB HDD storage.

Universal Flash Storage Association (UFSA) founded.

JEDEC publishes two specs for Solid-State Drives: "SSD Requirements and Endurance Test Method" and "SSD Endurance Workloads." LSI acquires SandForce.

SanDisk acquires Pliant.

IMFT introduces
20nm NAND flash.

Intel announces Smart Response Technology (SRT) SSD caching for PCs.

Seagate announces second generation
Momentus XT hybrid
HDD with 8GB NAND
flash and 750GB
HDD storage.

Apple acquires signal-processing controller IP firm Anobit.

Fusion-io acquires virtualization-aware flash caching software company IO Turbine.

NVMHCI renamed "NVM Express" (aka NVMe) and NVM Express Work Group established; NVMe Rev. 1.0 published.

JEDEC publishes first Universal Flash Storage (UFS) spec.

SNIA publishes two
Solid State Storage
Performance specs:
Enterprise and Client.

JEDEC publishes Serial Flash Discoverable Parameters (SFDP) spec.

Intel's 1988 NOR Flash
Memory Design Team of
Richard Pashley, Stefan
Lai, Bruce McCormick
and Niles Kynett receive
first FMS Lifetime
Achievement Awards.

\$28,213,759,000

\$29,797,262,000 \$30,236,484,000

\$31,053,183,000

SanDisk and Toshiba announce 19nm process in 128Gb chips at IEEE ISSCC.

Ultrabooks ship with Smart Response Technology (SRT) SSD cache.

Macronix and Winbond enter NAND business.

Seagate introduces SSHD, a Hybrid Hard Drive (HHD) pairing flash with an HDD.

Elpida introduces ReRAM.

Micron and Intel introduce 20nm 128Gb NAND chip using hi-k planar cell.

SK hynix formed upon SK Telecom's acquisition of controlling interest in Hynix Semiconductor.

MOSAID samples 333GB/s HL-NAND.

Adesto acquires ATMEL's Serial NOR business.

Spansion introduces 8Gb NOR chip.

DensBits Technologies introduces Memory Modem.

Proximal Data introduces AutoCache.

SanDisk acquires FlashSoft.

EMC acquires XtremIO.

OCZ acquires Sanrad.

Samsung acquires NVELO.

Intel acquires Nevex and introduces CacheWorks.

LSI introduces Nytro flash with MegaRAID Cache-Cade caching software.

Micron introduces 2.5" PCle enterprise SSD.

IBM acquires Texas Memory Systems.

Cypress Semiconductor acquires Ramtron.

Western Digital acquires

HGST. JEDEC and ONFi

introduce toggle mode.

SNIA forms NVM Programming TWG.

SanDisk founder Eli Harari receives FMS Lifetime

Achievement Award.

Samsung announces 24-layer 3D V-NAND at FMS and demos it in a 1TB SSD.

11 companies participate in first NVMe Plugfest.

Diablo Technologies announces Memory Channel Storage tech.

SMART Storage Systems incorporates Diablo Tech designs into ULLtraDIMM.

SNIA NVDIMM SIG formed; many NVDIMM products introduced.

Western Digital and SanDisk introduce SSHD using iSSD combined with a Hard Disk Drive.

Toshiba introduces line of SSHDs.

Everspin Technologies announces shipments of STT MRAM.

Micron and others sample 16nm flash memory.

SanDisk releases CFast 2.0 professional video memory card.

M.2 PCle interface formalized.

Western Digital acquires sTec, Virident, Velobit.

SanDisk acquires SMART Storage Systems.

NVMdurance introduces software to extend flash endurance.

Micron acquires Elpida.

Intel introduces Intel Cache Acceleration Software.

First UFS devices sampled by Toshiba at 8GB.

Panasonic ships first commercial embedded ReRAM in an MCU.

Adesto ships Mavriq CBRAM: first commercial stand-alone ReRAM.

SNIA publishes NVM Programming Model V1.0.

Fujio Masuoka, formerly of Toshiba, receives FMS Lifetime Achievement Award.

Samsung, SanDisk and Toshiba announce 3D NAND production facilities.

SanDisk introduces 4TB Enterprise SSD.

Intel ships first NVMe SSD.

SanDisk announces 128GB microSD card, a 1000x increase in capacity on device's 10th anniversary.

IBM announces eXFlash DIMMs using SanDisk ULLtraDIMM's implementation of Diablo Memory-Channel Storage technology.

Samsung rolls out second generation 3D V-NAND with 32 layers.

Spansion introduces HyperFlash NOR with 333 MB/s HyperBus.

Toshiba acquires OCZ.

Everspin introduces and ramps production of ST-MRAM.

Samsung introduces 3-bit/cell 3D NAND SSDs.

Adesto ships onemillionth CBRAM.

SK hynix acquires Violin Memory's PCle SSD business.

Seagate acquires LSI/Avago storage business.

SanDisk acquires Fusion-io.

HGST acquires Skyera.

Samsung acquires Proximal Data.

Simon Sze, formerly of Bell Labs, receives FMS Lifetime Achievement Award.

Flash Memory Summit's 10th conference.

SanDisk introduces InfiniFlash storage system.

Cypress Semiconductor acquires Spansion.

Toshiba, Samsung, and

SanDisk announce 48-layer 3D NAND.

Intel and Micron announce 256Gb 3D NAND.

Samsung introduces first NVMe m.2 SSDs.

SanDisk introduces 200GB microSDXC UHS-1 card.

Cypress introduces 4MB serial FRAM.

Intel and Micron announce 3D XPoint Memory.

Intel announces 3D XPoint-based "Optane" DIMMs and SSDs.

Micron introduces device with CMOS Under 3D NAND Array (CUA).

SanDisk introduces 200GB microSD card.

Mellanox and partners demonstrate prestandard NVMe over Fabrics (NVMe-oF).

Pure Storage has IPO.

JEDEC publishes first DDR4 NVDIMM-N Persistent Memory Module spec.

LightNVM and Open-Channel SSD support added to Linux kernel.

Bob Norman, formerly of SanDisk and Micron, receives FMS Lifetime Achievement Award.



\$33,423,128,000 \$49,727,000,000 \$56,227,000,000 \$41,141,000,000

All major vendors ship 3D NAND products.

XMC breaks ground on first China-owned NAND flash fab.

Micron introduces 768Gb 3D NAND.

Western Digital acquires SanDisk.

Everspin announces 256Mb MRAM chips.

IBM adapts TLC to PCM.

Samsung ships 48-layer 3D NAND.

NVMe-oF (NVM Express over Fabrics) Rev. 1.0 published.

NVMe-oF products demonstrated by at least 12 vendors.

Toshiba introduces
Through-Silicon Via
(TSV) in 16-die stack
NAND.

Spin Transfer
Technologies delivers
fully functional STMRAM samples.

Micron launches Xccela Consortium.

Toshiba ships industry's first NVMe BGA "SSD on a chip."

Western Digital demonstrates prototype of the first 1TB SDXC card.

Adesto launches
CBRAM-based Moneta
family of ReRAM.

SFF Committee
becomes SNIA SFF
Technology Affiliate.

Kinam Kim, President of System LSI /
Semiconductor
Business at Samsung, receives FMS Lifetime Achievement Award.

Flash Memory market exceeds size of entire 1990 semiconductor market.

Microchip ships its 75-billionth SST SuperFlash-based device.

SK hynix announces 72-layer 3D NAND.

Toshiba migrates all new SSDs to 64-layer BiCS FLASH TLC.

Intel ships Optane (3D XPoint) SSD.

Intel's "Ruler standard" donated to Enterprise & Data Center SSD Form Factor (EDSFF) WG.

HPE acquires Nimble Storage and Simplivity.

Micron ships first stringstacked 3D NAND.

Samsung and Toshiba/WD announce 96-layer 3D NAND.

NGD Systems ships NVMe 24TB Computational Storage Device (CSD).

Everspin samples 1Gb STT MRAM chip.

Global Foundries introduces embedded eMRAM.

WD develops TLC on 64-layer 3D NAND.

JEDEC and SNIA win FMS Award for NVDIMM-N Standard.

ScaleFlux first to deploy production-qualified Computational Storage.

Eli Harari (2012 and 2022 FMS Lifetime Achievement Awardee) inducted into National Inventors Hall of Fame.

George Perlegos, formerly of Intel, SEEQ and ATMEL, receives FMS Lifetime Achievement Award. Cypress introduces 16Mb FRAMs.

Toshiba completes \$18B memory business sale.

Samsung launches high-speed Z-SSD.

Micron ships Enterprise SSD using QLC and 1Tb 3D NAND die.

Hyperstone introduces flash controllers with Al and Machine Learning.

Intel samples Optane (3D XPoint) DC
Persistent Memory DIMM.

China's "Big Fund"
Phase 2 targets over
\$30B for semiconductor
investments.

NVMe/TCP Transport Binding spec ratified by NVMe WG.

SNIA forms
Computational Storage
Technical Work Group
(TWG).

Gyrfalcon Technology ships Al accelerator incorporating first use of TSMC's eMRAM.

SNIA publishes
Performance specs for
Solid State Storage and
for Real World Storage
Workloads.

Amber Huffman of Intel receives first FMS SuperWomen in Flash Award.

Dov Moran and Aryeh Mergi, M-Systems co-founders, receive FMS Lifetime Achievement Awards. All major vendors ship or sample 96-Layer NAND; SK hynix, Samsung and Micron sample 128-layer NAND.

All leading foundries produce embedded MRAM (eMRAM).

Lightbits Labs ships first commercial NVMe/
TCP software-defined disaggregated storage.

YMTC samples 32-layer "Xtacking" NAND.

Intel ships Optane (3D XPoint) DIMMs.

Micron ships first QLC enterprise SSDs.

Intel ships SSDs with both Optane (3D XPoint) and QLC NAND.

Open-Channel SSDs begin transition to NVMe Zoned Namespaces (ZNS).

Computer Express Link (CXL) introduced, and Spec V1.1 published.

NGD Systems ships first scalable ASIC-based Computational Storage NVMe SSD.

Eideticom ships
first NVMe-based
Computational Storage
Processor.

SNIA publishes Key Value Store API V1.0, and wins FMS Award.

Toshiba Memory becomes KIOXIA.

Phison and AMD ship first PCle 4.0 x4 NVMe SSD and motherboard solution.

Calline Sanchez of IBM receives FMS SuperWomen in Flash Award.

Sanjay Mehrotra of Micron, and formerly of Intel, SEEQ, IDT, ATMEL, SanDisk and WD, receives FMS Lifetime Achievement Award.



\$50,714,000,000 \$60,481,000,000 \$72,577,000,000 (est)

Flash Memory Summit's 15th conference (held as a virtual online-only event).

WDC ships 112-layer
BiCS 3D NAND as 512
Gbit TLC part.

KIOXIA ships first Automotive UFS at 512GB density.

Lightbits Labs ships first clustered, redundant, scale-out NVMe/TCP software solution.

Infineon acquires
Cypress Semiconductor.

KIOXIA acquires LiteOn.

NVMe ZNS Command Set Spec V1.0 published.

NVMe Computational Storage Task Group formed.

Open Compute Project (OCP) publishes NVMe Cloud SSD Spec V1.0: first Cloud SSD reqs. spec.

JEDEC publishes first DDR4 NVDIMM-P Persistent Memory Module spec.

JEDEC publishes DDR5 SDRAM standard and Universal Flash Storage (UFS) Card Extension 3.0 standard.

SNIA publishes specs for Native NVMe-oF and Cloud Data Mgmnt. Interface (CDMI).

KIOXIA ships first PCle 4.0 x4 Enterprise NVMe SSD.

Dialog Semiconductor acquires Adesto
Technologies.

DNA Data Storage Alliance launched.

Barbara Murphy of WekalO receives FMS SuperWomen in Flash Award.

John R. Szedon, formerly of Westinghouse, receives FMS Lifetime Achievement Award. NOR revenues exceed \$3.6B.

KIOXIA and WDC announce 162-layer 3D NAND.

Samsung announces the first DRAM-based memory running on CXL, based on DDR5.

JEDEC publishes
XFM (Crossover Flash
Memory) Embedded
and Removable Memory
Device standard.

SK hynix begins acquisition of Intel's NAND and SSD business, to be branded as Solidigm.

NVIDIA launches
GPUDirect Storage
(GDS), providing a direct
NVMe-to-GPU data
path.

KIOXIA and Samsung announce PCle 5.0 x4 Enterprise NVMe SSDs.

Renesas acquires Dialog Semiconductor.

NVMe 2.0 standard released as a set of 9 specs: base, 3 cmd. sets, 4 transports, and Management I/F.

SK hynix starts mass production of 176-layer "4D" NAND.

of NAND Flash:
proposed by Toshiba's
Fujio Masuoka
(2013 FMS Lifetime
Achievement Awardee)
in an IEEE IEDM
paper; industry-wide
celebration at Flash
Memory Summit.

PCI-SIG releases PCIe 6.0 spec.

Universal Chiplet
Interconnect Express
(UCle) 1.0 Spec released
to standardize die-todie interconnects.

JEDEC publishes
HBM3 update to High
Bandwidth Memory
(HBM) DRAM standard.

Micron ships first 176-layer QLC 3D NAND and announces 232-Layer TLC 3D NAND.

Lightbits Labs ships first clustered NVMe/TCP software-defined public cloud storage solution.

Yan Li of Western
Digital receives FMS
SuperWomen in Flash
Award.

Yoshishige Kitamura (formerly of NEC),
SanDisk founder Eli
Harari (2012 FMS
Lifetime Achievement
Awardee), and Greg
Atwood (formerly of
Intel, Numonyx, and
Micron) receive FMS
Lifetime Achievement
Awards.